

P-Channel Enhancement Mode MOSFET

1. Product Information

1.1 Features

- ☑ Surface-mounted package
- ☑ Low gate charge

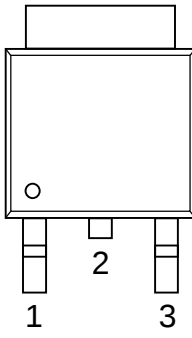
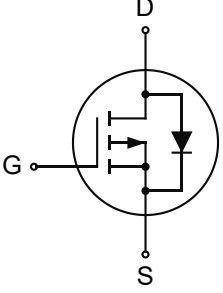
1.2 Applications

- ☑ Motor driver appliances
- ☑ High power inverter system
- ☑ Adapter appliances

1.3 Quick reference

- ☑ $BV \geq -60V$
- ☑ $R_{DS(ON)} \leq 20m\Omega @ V_{GS} = -10V$
- ☑ $P_{tot} \leq 50W$
- ☑ $R_{DS(ON)} \leq 28m\Omega @ V_{GS} = -4.5V$
- ☑ $I_D \leq -50A$

2. Pin Description

Pin	Description	Simplified Outline	Symbol
1	Gate(G)	 Top View TO-252	
2	Drain(D)		
3	Source(S)		

3. Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	Drain-Source Voltage	$T_C=25^{\circ}\text{C}$	-60	-	V
V_{GS}	Gate-Source Voltage	$T_C=25^{\circ}\text{C}$	-	± 20	V
I_D^*	Drain Current (DC)	$T_C=25^{\circ}\text{C}, V_{GS}=-10\text{V}$	-	-50	A
		$T_C=100^{\circ}\text{C}, V_{GS}=-10\text{V}$	-	-24	A
$I_{DM}^{*,**,***}$	Drain Current (Pulsed)	$T_C=25^{\circ}\text{C}, V_{GS}=-10\text{V}$	-	-120	A
P_{tot}	Drain power dissipation	$T_C=25^{\circ}\text{C}$	-	50	W
T_{stg}	Storage Temperature		-55	150	$^{\circ}\text{C}$
T_J	Junction Temperature		-	150	$^{\circ}\text{C}$
I_S	Diode Forward Current	$T_C=25^{\circ}\text{C}$	-	-50	A
E_{AS}^*	Single Pulsed Avalanche Energy	$V_{DD}=50\text{V}, L=1.0\text{mH}$	-	276	mJ
$R_{\theta JA}^*$	Thermal Resistance-Junction to Ambient		-	50	$^{\circ}\text{C/W}$
$R_{\theta JC}^*$	Thermal Resistance-Junction to Case		-	2.5	

Notes :

- * Surface Mounted on 1 in² pad area, $t \leq 10$ sec
- ** Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$
- *** Limited by bonding wire

4. Marking Information

Product Name	Marking
KJ50P06K	50P06 YWWXXX YWW: Date Code

5. Ordering Code

Product Name	Package	Reel Size	Tape width	Quantity	Note
KJ50P06K	TO252			2500	

Note: KJ50P06K defines “ Green ” as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC / JEDEC J-STD-020C)

6. Electrical Characteristics (T_A=25°C Unless Otherwise Noted)

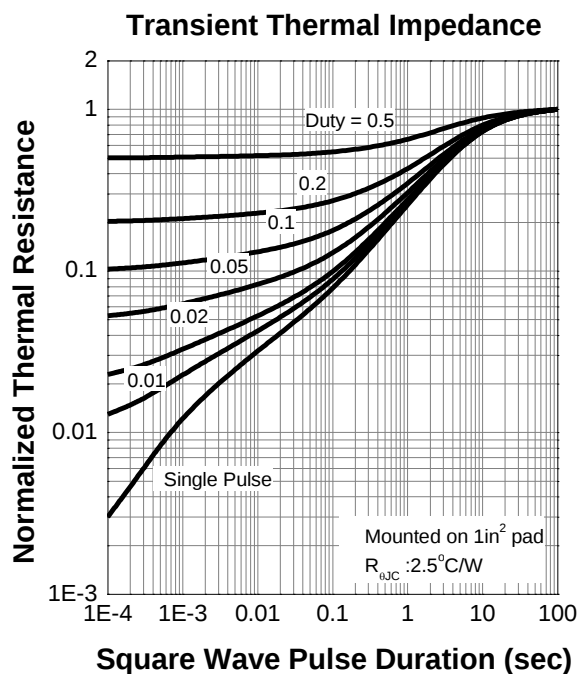
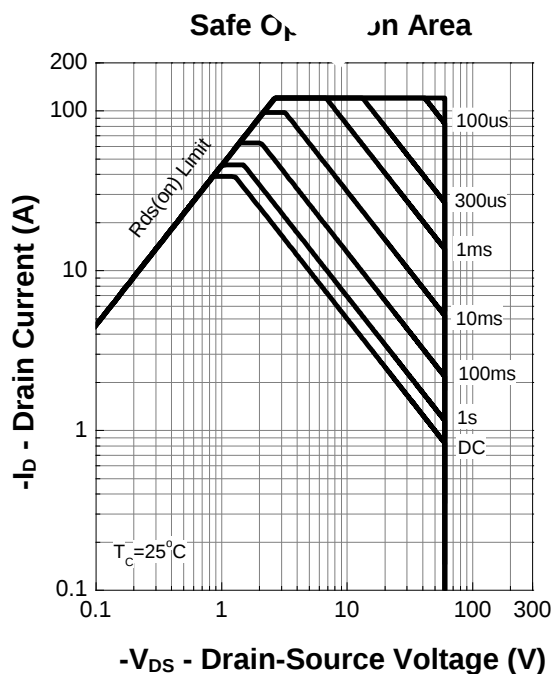
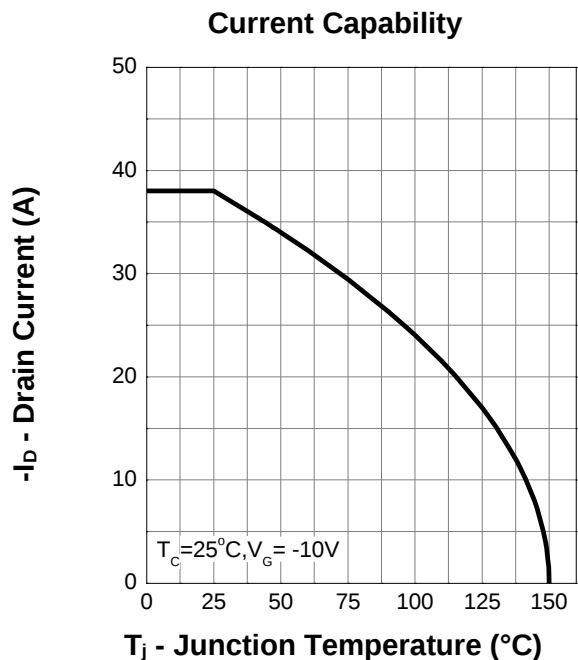
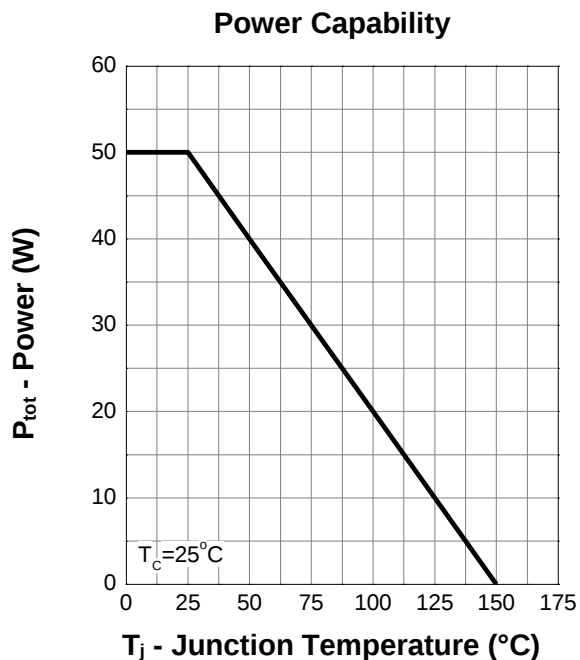
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
Static Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _{DS} =-250μA	-60	-	-	V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _{DS} =-250μA	-1	-	-3	V
I _{DSS}	Drain Leakage Current	V _{DS} =-48V, V _{GS} =0V	-	-	-1	μA
I _{GSS}	Gate Leakage Current	V _{GS} =0V, V _{GS} =±20V	-	-	±100	nA
R _{DS(ON)} ^a	On-State Resistance	V _{GS} =-10V, I _{DS} =-15A	-	18	20	mΩ
		V _{GS} =-4.5V, I _{DS} =-10A	-	25	28	
Diode Characteristics						
V _{SD} ^a	Diode Forward Voltage	I _{SD} =-15A, V _{GS} =0V	-	-	-1.3	V
t _{rr}	Reverse Recovery Time	I _{SD} =-15A, dI _{SD} /dt=100A/μs	-	23	-	ns
Q _{rr}	Reverse Recovery Charge		-	23	-	nC
Dynamic Characteristics ^b						
C _{iss}	Input Capacitance	V _{GS} =0V, V _{DS} =-30V Frequency=1MHz	-	4584	-	pF
C _{oss}	Output Capacitance		-	178	-	
C _{rss}	Reverse Transfer Capacitance		-	133	-	
t _{d(on)}	Turn-on Delay Time	V _{DS} =-30V, V _{GEN} =-10V, R _G =3.9Ω, R _L =2Ω, I _{DS} =-15A	-	66	-	ns
t _r	Turn-on Rise Time		-	101	-	
t _{d(off)}	Turn-off Delay Time		-	465	-	
t _f	Turn-off Fall Time		-	205	-	
Gate Charge Characteristics ^b						
Q _g	Total Gate Charge	V _{DS} =-30V, V _{GS} =-10V, I _{DS} =-15A	-	72	-	nC
Q _{gs}	Gate-Source Charge		-	19	-	
Q _{gd}	Gate-Drain Charge		-	9.8	-	

Notes:

a: Pulse test ; pulse width ≤ 300 μs, duty cycle ≤ 2%

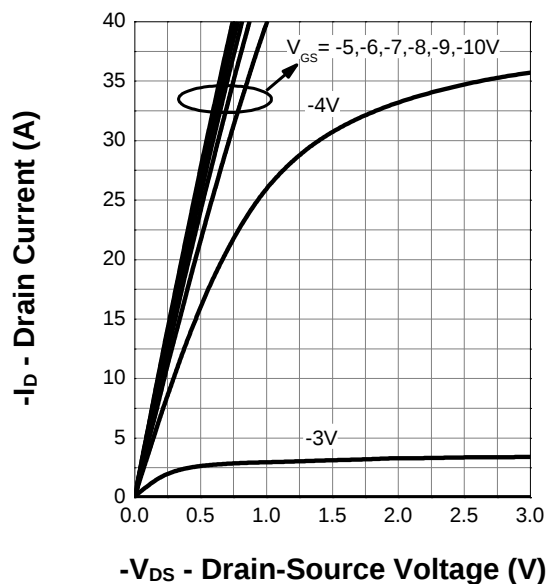
b: Guaranteed by design, not subject to production testing

7. Typical Characteristics

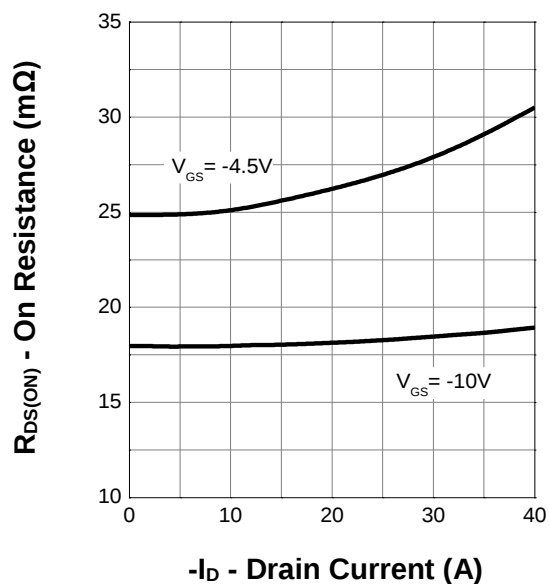


7. Typical Characteristics (Cont.)

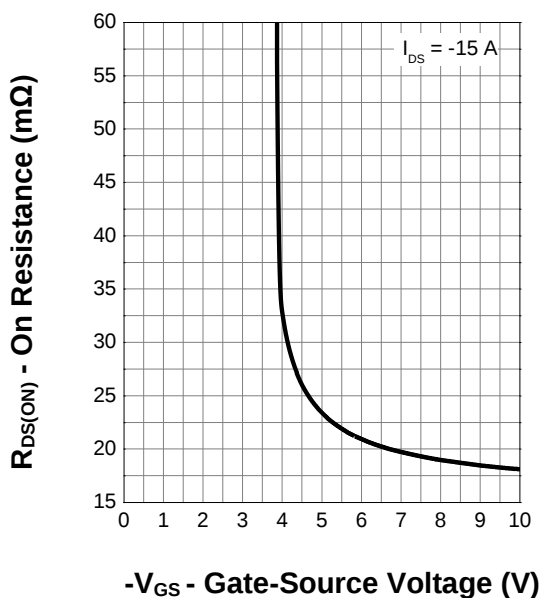
Output Characteristics



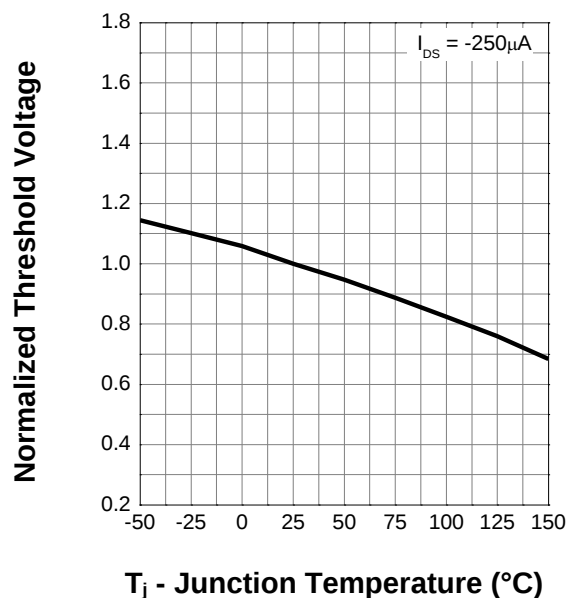
Drain-Source On Resistance



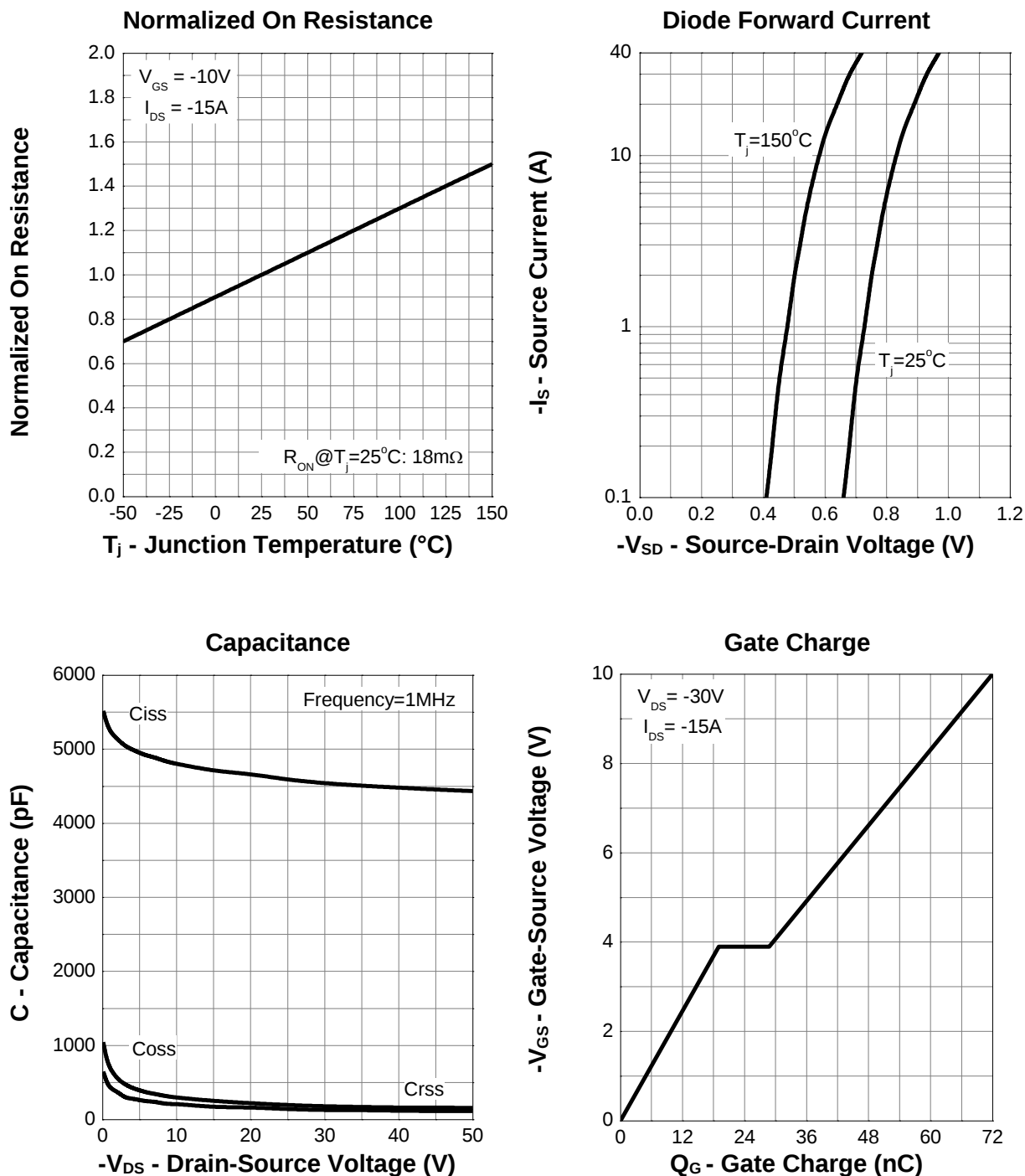
Transfer Characteristics



Normalized Threshold Voltage

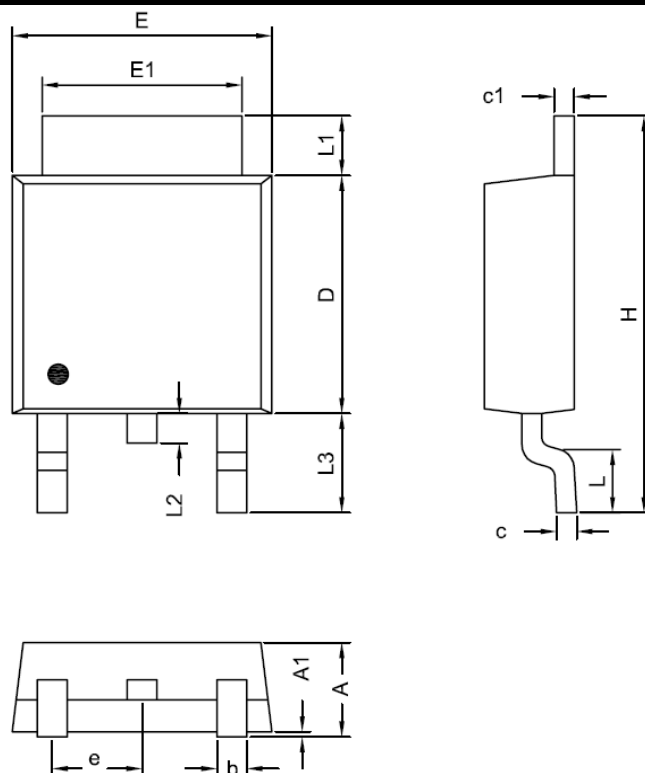


7. Typical Characteristics (Cont.)



8. Package Dimensions

TO-252 Package



Symbol	Dimensions In Millimeters	
	MIN.	MAX.
A	2.19	2.38
A1	0.02	0.13
D	5.30	6.40
E	6.35	6.80
E1	5.20	5.50
c	0.40	0.60
c1	0.40	0.60
b	0.55	0.85
e	2.30 BCS	
L	1.00	1.80
L1	0.70	1.80
L2	0.70 BCS	
L3	2.40	2.80
H	9.20	10.40